

LC35256FM, FT-55U/70U

256K (32768 words × 8 bits) SRAM Control Pins: OE and CE

Preliminary

Overview

The LC35256FM and LC35256FT are asynchronous silicon-gate CMOS SRAMs with a 32K-word by 8-bit structure. These are full-CMOS devices with 6 transistors per memory cell, and feature low-voltage operation, a low operating current drain, and an ultralow standby current. Control inputs include \overline{OE} for fast memory access and \overline{CE} (chip enable) for power saving and device selection. This makes these devices optimal for systems that require low power or battery backup, and makes memory expansion easy. The ultralow standby current allows these devices to be used with capacitor backup as well.

Features

• Supply voltage range: 4.5 to 5.5 V

• Access time at 5 V operation:

LC35256FM, FT-55U: 55 ns (maximum) LC35256FM, FT-70U: 70 ns (maximum)

• Standby current: $3.0 \mu A (Ta \le 70^{\circ}C)$

 $5.0 \,\mu\text{A} \,(\text{Ta} \le 85^{\circ}\text{C})$

• Operating temperature: -40 to +85°C

• Data retention voltage: 2.0 to 5.5 V

• All I/O levels: TTL compatible

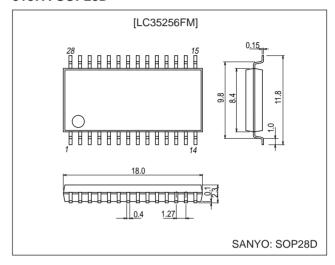
- Input/output shared function pins, 3-state output pins
- · No clock required
- Package

28-pin SOP (450 mil) plastic package: LC35256FM 28-pin TSOP (8 × 13.4 mm) plastic package: LC35256FT

Package Dimensions

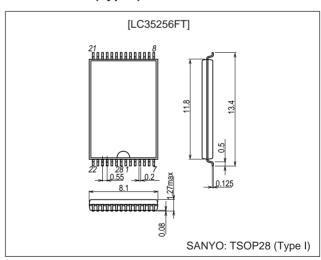
unit: mm

3187A-SOP28D



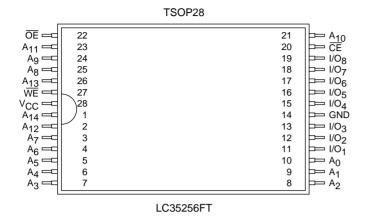
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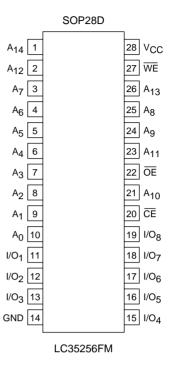
3221-TSOP28 (Type I)



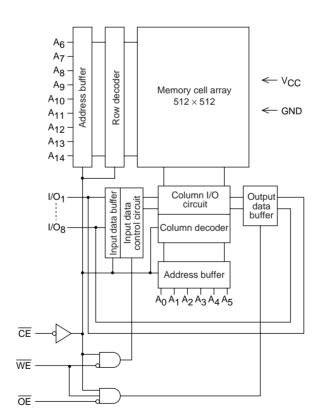
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Pin Assignment (Top view)





Block Diagram



Pin Functions

A0 to A14	Address input
WE	Read/write control input
ŌĒ	Output enable input
CE	Chip enable input
I/O1 to I/O8	Data I/O
V _{CC} , GND	Power supply, ground

Function Table

Mode	CE	ŌE	WE	I/O	Supply current
Read cycle	L	L	Н	Data output	I _{CCA}
Write cycle	L	Х	L	Data input	I _{CCA}
Output disable	L	Н	Н	High impedance	I _{CCA}
Unselected	Н	Х	Х	High impedance	Iccs

SpecificationsAbsolute Maximum Ratings

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max		7.0	V
Input pin voltage	V _{IN}		-0.3* to V _{CC} + 0.3	V
I/O pin voltage	V _{I/O}		-0.3 to $V_{CC} + 0.3$	V
Operating temperature	Topr		-40 to +85	°C
Storage temperature	Tstg		-55 to +125	°C

Note: * The minimum value is -3.0 V for pulse widths under 30 ns.

I/O Capacitances at $Ta = 25^{\circ}C$, f = 1 MHz

Parameter	Symbol	Conditions		Unit		
Faianetei	Symbol	Conditions	min	typ	max	Ullit
I/O pin capacitance	C _{I/O}	V _{I/O} = 0 V		6	10	pF
Input pin capacitance	C _I	V _{IN} = 0 V		6	10	pF

Note: All units are not tested; only samples are tested.

DC Allowable Operating Ranges at Ta = -40 to $+85^{\circ}$ C, V_{CC} = 4.5 to 5.5 V

Parameter	Symbol	Conditions		Unit		
			min	typ	max	Offic
Supply voltage	V _{CC}		4.5	5.0	5.5	V
Input voltage	V _{IH}		2.2		V _{CC} + 0.3	V
Input voltage	V _{IL}		-0.3*		+0.8	V

Note: * The minimum value is -3.0 V for pulse widths under 30 ns.

LC35256FM, FT-55U/70U

DC Electrical Characteristics at $Ta = -40~to~+85^{\circ}C,\,V_{CC} = 4.5~to~5.5~V$

Parameter		Symbol	Cons	litions			Ratings		Unit
Farameter		Symbol	Conc	11110115		min	typ*	max	Ullit
Input leakage current		ILI	V _{IN} = 0 to V _{CC}			-1.0		+1.0	μA
Output leakage current		I _{LO}	$V_{\overline{CE}} = V_{IH} \text{ or } V_{\overline{OE}} = V_{IH} \text{ or } V_{\overline{WE}} = V_{IL},$ $V_{I/O} = 0 \text{ to } V_{CC}$			-1.0		+1.0	μA
Output high-level voltage		V _{OH}	I _{OH} = -1.0 mA			2.4			V
Output low-level voltage		V _{OL}	I _{OL} = 2.0 mA					0.4	V
	I _{CCA2}	$V_{CE} = V_{IL}$, $I_{I/O} = 0$ mA, $V_{IN} = V_{IH}$ or V_{IL}					5.0	mA	
Operating current drain	TTI inputo	4-	Duty 100.0/	Min.	LC35256FM, FT-55U		40	45	
Operating current drain	TTL inputs	I _{CCA3}		or V_{IL} , $I_{I/O} = 0$ mA, cycle LC35256FM, FT-70U			35	40	mA
				1 µs c	/cle		3.5	6.0	
					Ta ≤ 25°C		0.05		
Ctondby mode	V _{CC} – 0.2 V/		$V_{\overline{CE}} \ge V_{CC} - 0.2 \text{ V},$		Ta ≤ 60°C			1.5	
Standby mode current drain 0.2 V inputs	0.2 V inputs	I _{CCS1}	$V_{IN} = 0$ to V_{CC}		Ta ≤ 70°C			3.0	μA
					Ta ≤ 85°C			5.0	
	TTL inputs	I _{CCS2}	$V_{\overline{CE}} = V_{IH}, V_{IN} = 0 \text{ to}$	V _{CC}				1.0	mA

Note: * Reference values when $V_{CC} = 5 \text{ V}$ and $Ta = 25^{\circ}\text{C}$.

AC Electrical Characteristics at Ta = -40 to $+85^{\circ}C$, $V_{CC} = 4.5$ to 5.5~V

AC test conditions

Input pulse voltage levels: $V_{IH} = 2.4 \text{ V}$, $V_{IL} = 0.6 \text{ V}$

Input rise and fall times: 5 ns

Input and output timing levels: 1.5 V

Output load: 30 pF + 1 TTL gate (including the jig capacitance)

Read Cycle

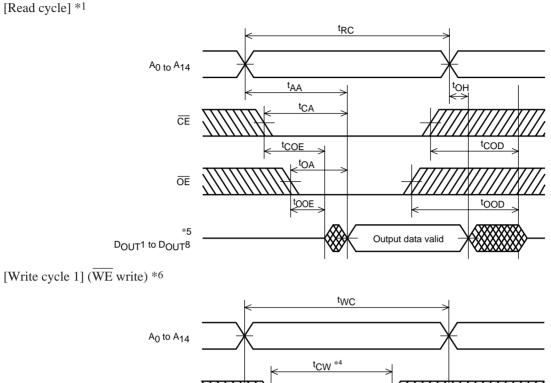
	Symbol					
Parameter		-55U		-70	Unit	
		min	max	min	max	
Read cycle time	t _{RC}	55		70		ns
Address access time	t _{AA}		55		70	ns
CE access time	t _{CA}		55		70	ns
OE access time	t _{OA}		30		35	ns
Output hold time	t _{OH}	10		10		ns
CE output enable time	t _{COE}	5		10		ns
OE output enable time	tooe	5		5		ns
CE output disable time	t _{COD}		20		30	ns
OE output disable time	t _{OOD}		20		25	ns

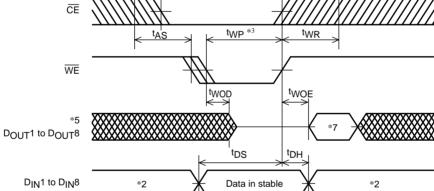
Write Cycle

		LC35256FM, FT				
Parameter	Symbol	-55U		-70U		Unit
		min	max	min	max	
Write cycle time	t _{WC}	55		70		ns
Address setup time	t _{AS}	0		0		ns
Write pulse width	t _{WP}	40		50		ns
CE setup time	t _{CW}	50		60		ns
Write recovery time	t _{WR}	0		0		ns
CE write recovery time	t _{WR1}	0		0		ns
Data setup time	t _{DS}	25		30		ns
Data hold time	t _{DH}	0		0		ns
CE data hold time	t _{DH1}	0		0		ns
WE output enable time	t _{WOE}	5		5		ns
WE output disable time	t _{WOD}		20		30	ns

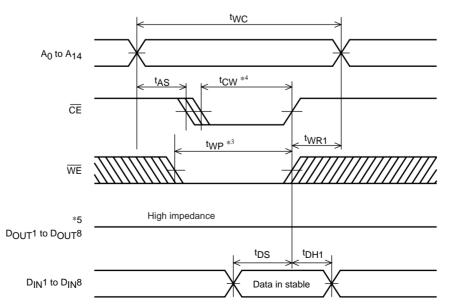
Timing Charts

[Read cycle] *1





[Write cycle 2] (CE write) *6



LC35256FM, FT-55U/70U

Notes:1. WE must be held at the high level during the read cycle.

- 2. Do not apply reverse phase signals to the D_{OUT} pins when those pins are in the output state.

 3. The time t_{WP} is the period when both CE and WE are low. It is defined as the time from the fall of WE to the rise of CE or WE, whichever occurs
- 4. The time t_{CW} is the period when both $\overline{\text{CE}}$ and $\overline{\text{WE}}$ are low. It is defined as the time from the fall of $\overline{\text{CE}}$ to the rise of $\overline{\text{CE}}$ or $\overline{\text{WE}}$, whichever occurs first.
- 5. The D_{OUT} pins will be in the high-impedance state if any one of the following hold: \overline{OE} is at the high level, \overline{CE} is at the high level, or \overline{WE} is at the low level
- 6. The $\overline{\text{OE}}$ pin must be either held high or held low during the write cycle.
- 7. D_{OUT} has the same phase as the write data during this write cycle.

Circuit Design Notes

When designing application circuits, always take the following into consideration and design the circuits so that the absolute maximum ratings are never exceeded.

- Supply voltage fluctuations
- Sample-to-sample variations in the electrical characteristics of the electronic components used, including semiconductor devices, resistors, and capacitors.
- Ambient temperature
- Variations in the input and clock signals
- The application of abnormal pulses

Furthermore, be sure to operate this device within the stipulated ranges of all parameters for which an allowable operating range is specified.

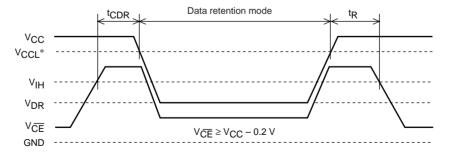
When CMOS IC input pins are left in the open state, through currents may occur in internal circuits to which intermediate voltage levels are applied, and this can result in incorrect circuit operation. Be sure to handle all unused input pins as specified in the device documentation.

Data Retention Conditions at $Ta = -40 \text{ to } +85^{\circ}\text{C}$

Parameter	Symbol	Con	min	typ*	max	Unit	
Data retention supply voltage	V_{DR}	$V_{\overline{CE}} \ge V_{CC} - 0.2 \text{ V}$		2.0		5.5	V
Data retention supply current	ICCDR		Ta ≤ 25°C		0.02		
		V _{CC} = 3.0 V	Ta ≤ 60°C			1.0	
		$V_{\overline{CE}} \ge V_{CC} - 0.2 \text{ V}$	Ta ≤ 70°C			2.0	μΑ
			Ta ≤ 85°C			3.5	
Chip enable setup time	t _{CDR}			0			ns
Chip enable hold time	t _R			t _{RC} **			ns

Note: * Reference values for $V_{CC} = 3 \text{ V}$, $Ta = 25 ^{\circ}\text{C}$.

Data Retention Waveforms



Note: * V_{CCL} 5 V operation: 4.5 V

^{**} t_{RC}: Read cycle time

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